

6th Generation CoolSiC[™]

650V SiC Schottky Diode

The CoolSiCTM generation 6 (G6) is the leading edge technology from Infineon for the SiC Schottky barrier diodes. The Infineon proprietary innovative G5 technology was enhanced in G6 by introducing further advancements like a novel Schottky metal system. The result is a family of products with improved efficiency over all load conditions, resulting from a lower figure of merit ($Q_c \times V_f$). The CoolSiCTM Schottky diode 650 V G6 has been designed to complement our 600 V and 650 V CoolMOSTM 7 families, meeting the most stringent application requirements in this voltage range.

Table 1 Key pe	meters		
Parameter	Value	Unit	
V _{RRM}	650	V	
$Q_{c} (V_{R} = 400 \text{ V})$	6.9	nC	
$E_{C} (V_{R} = 400 \text{ V})$	1.1	μJ	
$I_F \ (T_C \le 150 \ ^{\circ}\text{C}, D = 1)$	4	A	
$V_F (I_F = 4 \text{ A}, T_j = 25 \text{ °C})$	1.25	V	

Type / ordering Code	Package	Marking		
IDH04G65C6	PG-TO220-2	D0465C6		

Features

- Best in class forward voltage (1.25 V)
- Best in class figure of merit ($Q_c \times V_F$)
- High dv/dt ruggedness (150 V/ns)

Benefits

- System efficiency improvement
- System cost and size savings due to the reduced cooling requirements
- Enabling higher frequency and increased power density

Potential Applications

- Power factor correction in SMPS
- Solar inverter
- Uninterruptible power supply

Product Validation

• Qualified for industrial applications according to the relevant tests of JEDEC (J-STD20 and JESD22)

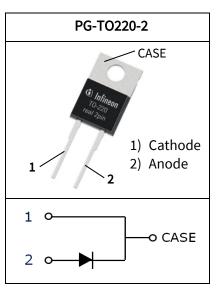






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Maximum ratings 1

Table 3 **Maximum ratings**

Parameter	Sumahal	Values			11	Nete/Testessadities
	Symbol	Min.	Тур.	Max.	Unit	Note/Test condition
		-	-	4		$T_c \le 150 ^{\circ}\text{C}, D = 1$
Continuous forward current	I_F	-	-	7		$T_c \le 125 ^{\circ}\text{C}, D = 1$
		-	-	12		$T_c \le 25 ^{\circ}\text{C}, D = 1$
Surge-repetitive forward current, sine halfwave ¹	I _{F,RM}	-	-	18	A	$T_c = 25 \text{ °C}, t_p = 10 \text{ ms}$
Surge non-repetitive forward	,	-	-	29		$T_c = 25 ^{\circ}\text{C}, t_p = 10 \text{ms}$
current, sine halfwave	I _{F,SM}	-	-	23		$T_c = 150 ^{\circ}\text{C}, t_p = 10 \text{ms}$
Non-repetitive peak forward current	I _{F,max}	-	-	250		$T_c = 25 \text{ °C}, t_p = 10 \mu\text{s}$
24	∫i²dt	-	-	4.3	A ² c	$T_c = 25 ^{\circ}\text{C}, t_p = 10 \text{ms}$
i ² t value	JI-al	-	-	2.7	– A²s	$T_c = 150 ^{\circ}\text{C}, t_p = 10 \text{ms}$
Repetitive peak reverse voltage	V _{RRM}	-	-	650	۷	<i>T_c</i> = 25 °C
Diode dv/dt ruggedness	dv/dt	-	-	150	V/ns	$V_R = 0480 \text{ V}$
Power dissipation	P _{tot}	-	-	45	W	$T_c = 25^{\circ}\text{C}, R_{thJC,max}$
Operating and storage temperature	$\begin{bmatrix} T_j \\ T_{stg} \end{bmatrix}$	-55	-	175	°C	-
Mounting torque	-	_	-	70	Ncm	M3 screw

Thermal characteristics 2

Thermal characteristics (PG-TO-220-2) Table 4

Deremeter	Symphol		Values		Unit	Note/Test condition
Parameter	Symbol	Min.	Тур.	Max.		
Thermal resistance, junction- case	$R_{ m thJC}$	-	2.0	3.4	K/W	-
Thermal resistance, junction- ambient	R _{thJA}	_	-	62		leaded
Soldering temperature, wavesoldering only allowed at leads	T _{sold}	_	_	260	°C	1.6 mm (0.063 in.) from case for 10 s

¹ The surge-repetitive forward current test was performed with 1000 pulses (half-wave rectified sine with the 10 ms period). **Final Datasheet** 3



3 Electrical characteristics

3.1 Static characteristics

Table 5Static characteristics

Parameter	Symbol	Values			11	Note/Test soudition
		Min.	Тур.	Max.	Unit	Note/Test condition
DC blocking voltage	V _{DC}	650	-	_		<i>T_j</i> = 25 °C
Diode forward voltage	V _F	_	1.25	1.35	V	<i>I</i> _{<i>F</i>} = 4 A, <i>T</i> _{<i>j</i>} = 25 °C
		_	1.5	_		<i>I_F</i> = 4 A, <i>T_j</i> = 150 °C
Reverse current	I _R	_	0.4	14		V_R = 420 V, T_j = 25 °C
		_	13	_	μA	V_R = 420 V, T_j = 125 °C
		-	31	-		V_R = 420 V, T_j = 150 °C

3.2 AC characteristics

Table 6AC characteristics

Parameter	Symbol	Values			11	Nata /Tast Can dition
		Min.	Тур.	Max.	Unit	Note/Test Condition
Total capacitive charge	0	-	6.9	-	nC	V_R = 400 V, T_j = 150 °C,
	Qc					$di/dt = 200 \text{ A}/\mu \text{s}, I_F \leq I_{F,MAX}$
Total capacitance			205 –			$V_R = 1 \text{ V, } f = 1 \text{ MHz,}$
		-			<i>T_j</i> = 25 °C	
	C	- 1	12	_	pF	V_R = 300 V, f = 1 MHz,
	С					<i>T_j</i> = 25 °C
			10			V_R = 600 V, f = 1 MHz,
	- 12 -	-		<i>T_j</i> = 25 °C		



4 Diagrams

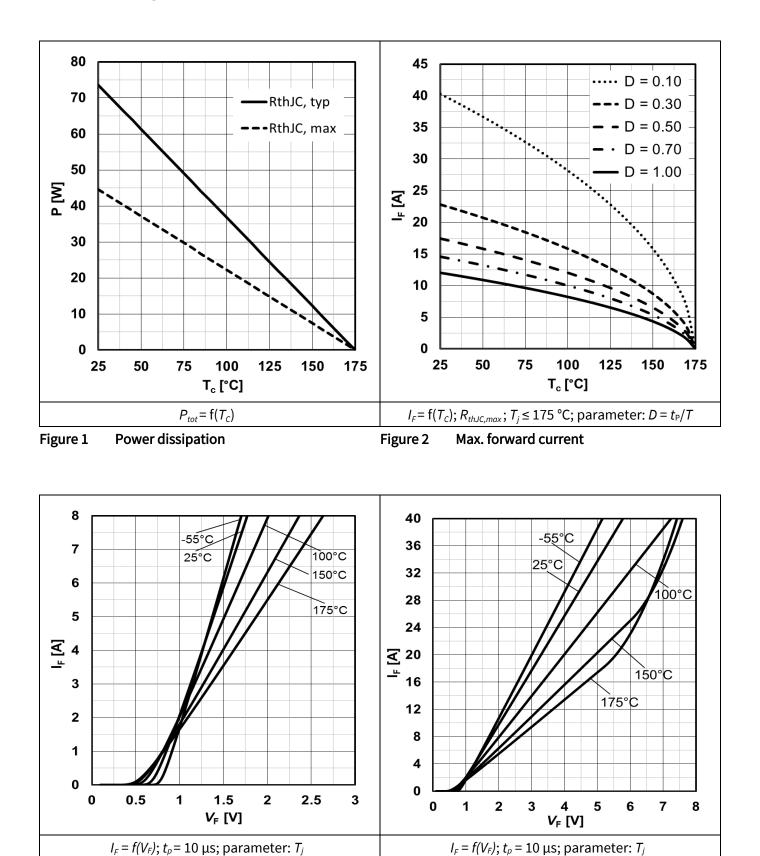
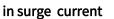


Figure 3 Typ. forward characteristics Figure 4 Typ. forward characteristics



6th Generation CoolSiC[™] IDH04G65C6

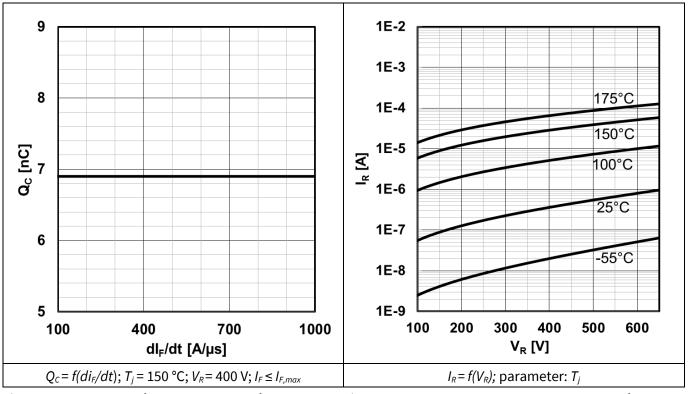
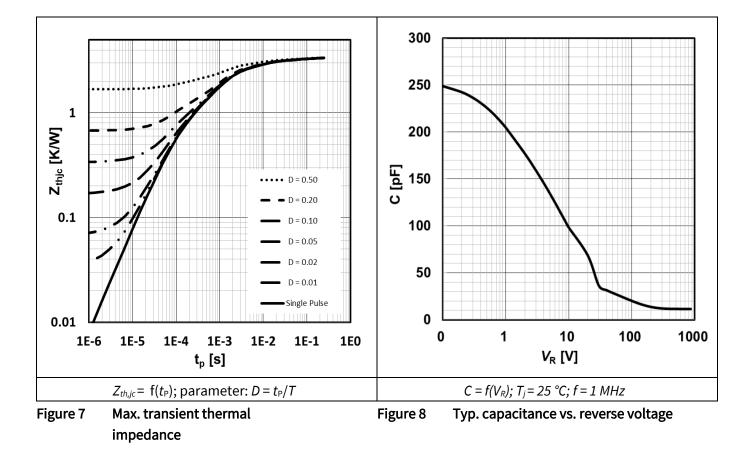


Figure 5 Typ. cap. charge vs. current slope

Figure 6 Typ. reverse current vs. reverse voltage



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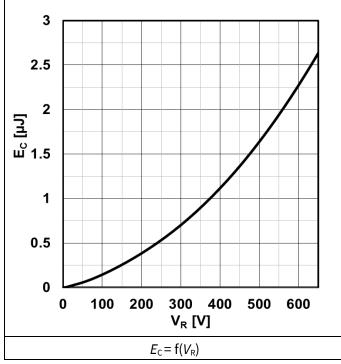
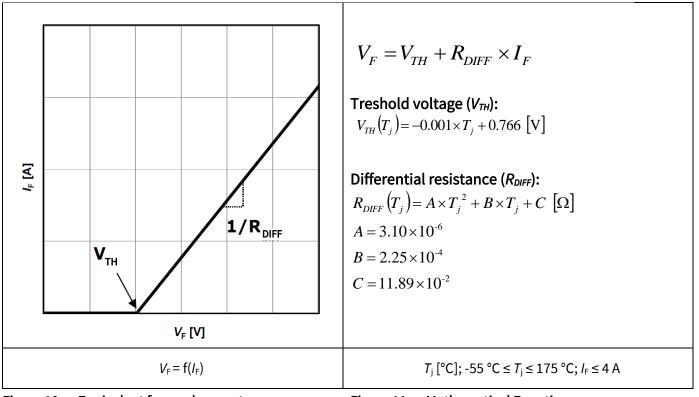


Figure 9 Typ. capacitance stored energy

5 Simplified forward characteristic



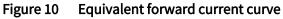


Figure 11 Mathematical Equation



6 Package outlines

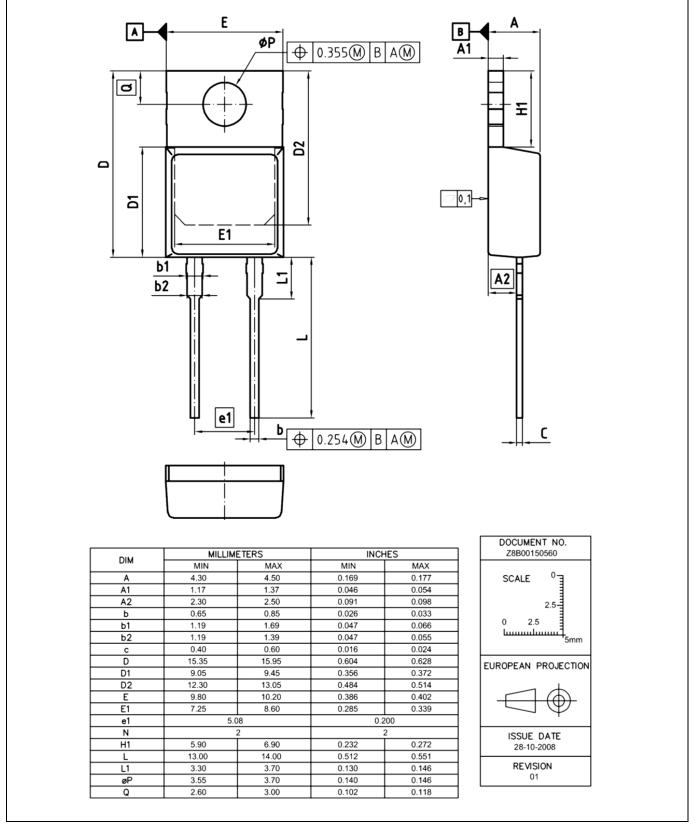


Figure 12 Outlines of the package PG-TO220-2, dimensions in mm/inches



Revision History

Major changes since the last revision

Revision	Date	Subject (major changes since last revision)					
2.0	2017-05-23	Release of final version					

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Document reference

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